

FQB47P06

P-Channel QFET® MOSFET

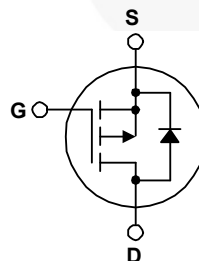
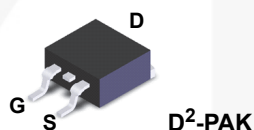
-60 V, -47 A, 26 mΩ

Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- -47 A, -60 V, $R_{DS(on)} = 26 \text{ m}\Omega$ (Max.) @ $V_{GS} = .10 \text{ V}$, $I_D = -23.5 \text{ A}$
- Low Gate Charge (Typ. 84 nC)
- Low C_{rss} (Typ. 320 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FQB47P06TM_AM002	Unit
V_{DSS}	Drain-Source Voltage	-60	V
I_D	Drain Current - Continuous ($T_C = 25^\circ\text{C}$)	-47	A
	- Continuous ($T_C = 100^\circ\text{C}$)	-33.2	A
I_{DM}	Drain Current - Pulsed (Note 1)	-188	A
V_{GSS}	Gate-Source Voltage	± 25	V
E_{AS}	Single Pulsed Avalanche Energy (Note 2)	820	mJ
I_{AR}	Avalanche Current (Note 1)	-47	A
E_{AR}	Repetitive Avalanche Energy (Note 1)	16	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	-7.0	V/ns
P_D	Power Dissipation ($T_A = 25^\circ\text{C}$) *	3.75	W
	Power Dissipation ($T_C = 25^\circ\text{C}$)	160	W
	- Derate above 25°C	1.06	W/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$
T_L	Maximum lead temperature for soldering, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	FQB47P06TM_AM002	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.94	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	
	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	40	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQB47P06TM_AM002	FQB47P06	D ² -PAK	Tape and Reel	330 mm	24 mm	800 units

Electrical Characteristics

$T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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Off Characteristics

BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-60	--	--	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$, Referenced to 25°C	--	-0.06	--	V/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -60\text{ V}, V_{GS} = 0\text{ V}$	--	--	-1	μA
		$V_{DS} = -48\text{ V}, T_C = 150^\circ\text{C}$	--	--	-10	μA
I_{GSSF}	Gate-Body Leakage Current, Forward	$V_{GS} = -25\text{ V}, V_{DS} = 0\text{ V}$	--	--	-100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = 25\text{ V}, V_{DS} = 0\text{ V}$	--	--	100	nA

On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-2.0	--	-4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = -10\text{ V}, I_D = -23.5\text{ A}$	--	0.021	0.026	Ω
g_{FS}	Forward Transconductance	$V_{DS} = -30\text{ V}, I_D = -23.5\text{ A}$	--	21	--	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = -25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$	--	2800	3600	pF
C_{oss}	Output Capacitance		--	1300	1700	pF
C_{rss}	Reverse Transfer Capacitance		--	320	420	pF

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -30\text{ V}, I_D = -23.5\text{ A},$ $R_G = 25\text{ }\Omega$	--	50	110	ns
t_r	Turn-On Rise Time		--	450	910	ns
$t_{d(off)}$	Turn-Off Delay Time		--	100	210	ns
t_f	Turn-Off Fall Time	(Note 4)	--	195	400	ns
Q_g	Total Gate Charge	$V_{DS} = -48\text{ V}, I_D = -47\text{ A},$ $V_{GS} = -10\text{ V}$	--	84	110	nC
Q_{gs}	Gate-Source Charge		--	18	--	nC
Q_{gd}	Gate-Drain Charge		--	44	--	nC

Drain-Source Diode Characteristics and Maximum Ratings

I _S	Maximum Continuous Drain-Source Diode Forward Current		--	--	-47	A
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current		--	--	-188	A
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = -47 A	--	--	-4.0	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = -47 A, dI _F / dt = 100 A/μs	--	130	--	ns
Q _{rr}	Reverse Recovery Charge		--	0.55	--	μC

Notes:

1. Repetitive rating : pulse-width limited by maximum junction temperature.
2. $L = 0.43\text{ mH}$, $I_{AS} = -47\text{ A}$, $V_{DD} = -25\text{ V}$, $R_G = 25\text{ }\Omega$, starting $T_J = 25^\circ\text{C}$.
3. $I_{SD} \leq -47\text{ A}$, $dI/dt \leq 300\text{ A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, starting $T_J = 25^\circ\text{C}$.
4. Essentially independent of operating temperature.

Typical Characteristics

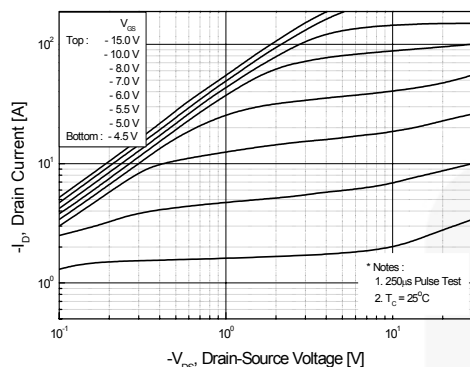


Figure 1. On-Region Characteristics

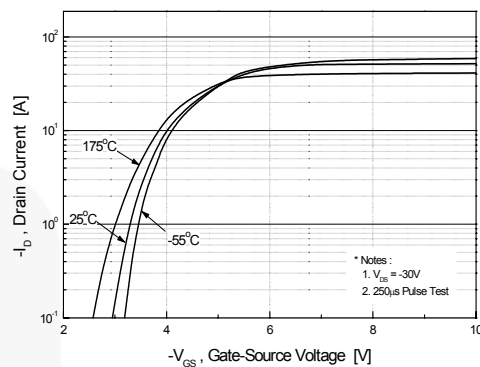


Figure 2. Transfer Characteristics

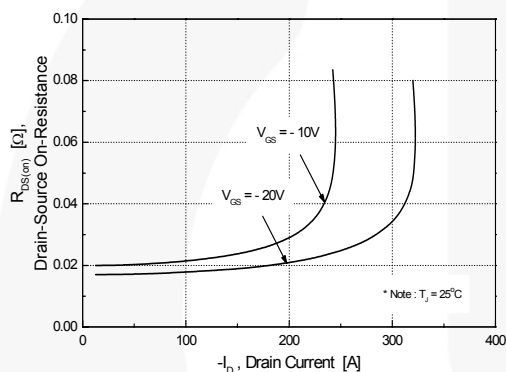


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

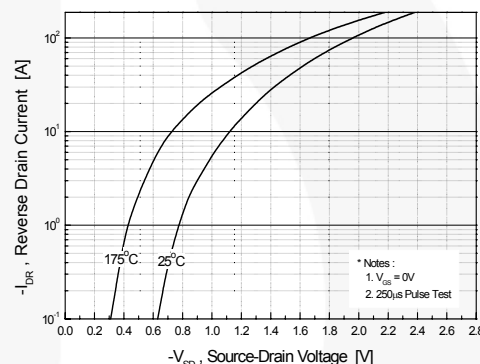
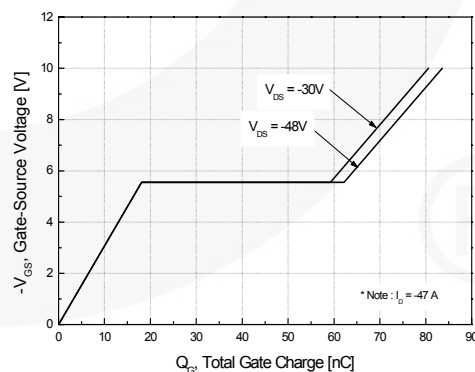
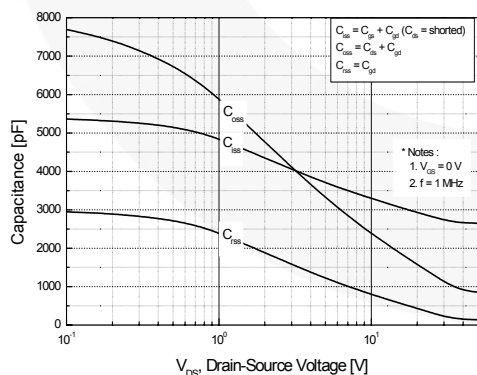


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature



Typical Characteristics (Continued)

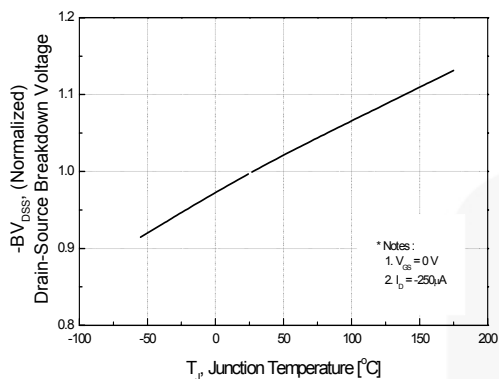


Figure 7. Breakdown Voltage Variation vs. Temperature

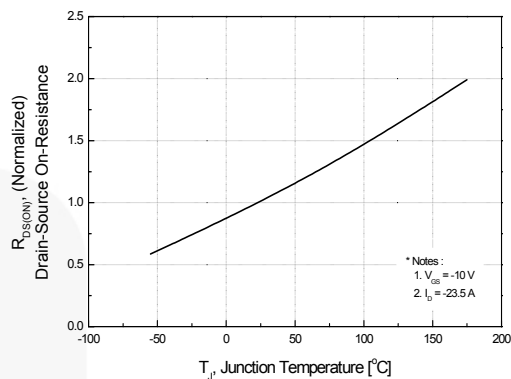


Figure 8. On-Resistance Variation vs. Temperature

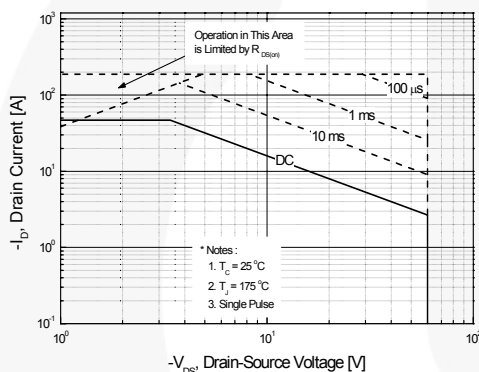


Figure 9. Maximum Safe Operating Area

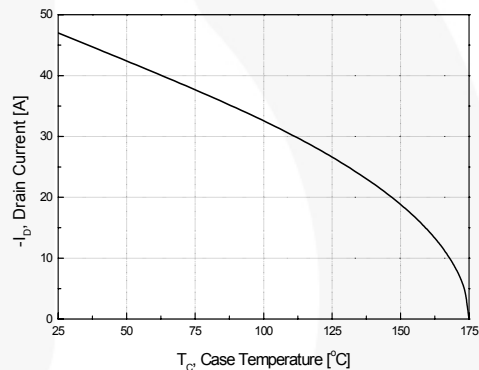


Figure 10. Maximum Drain Current vs. Case Temperature

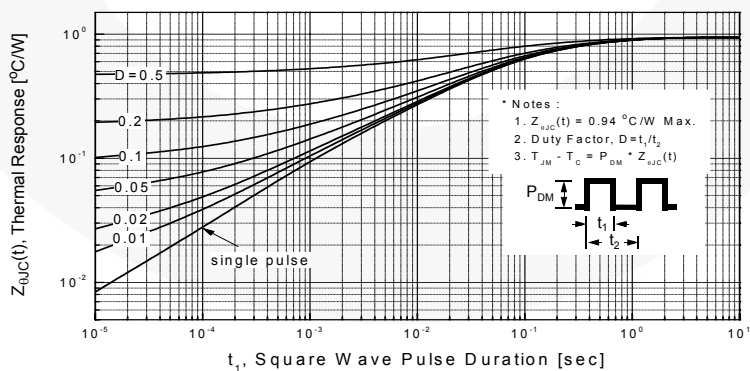


Figure 11. Transient Thermal Response Curve

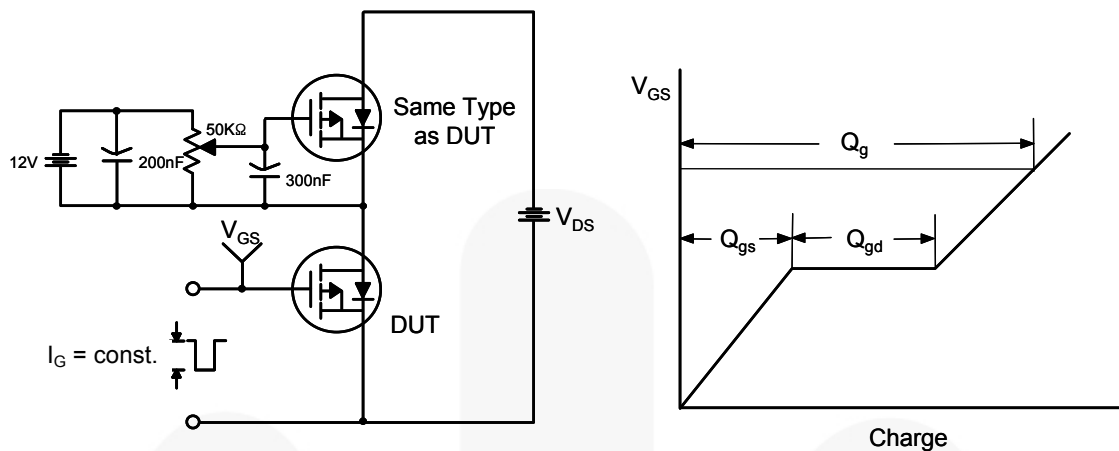


Figure 12. Gate Charge Test Circuit & Waveform

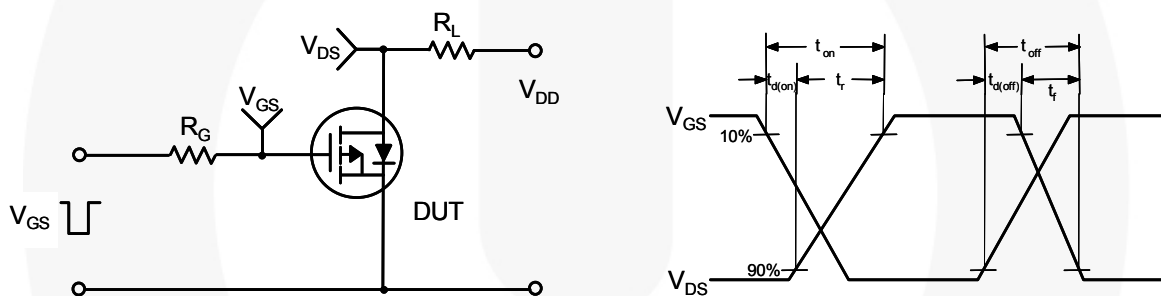


Figure 13. Resistive Switching Test Circuit & Waveforms

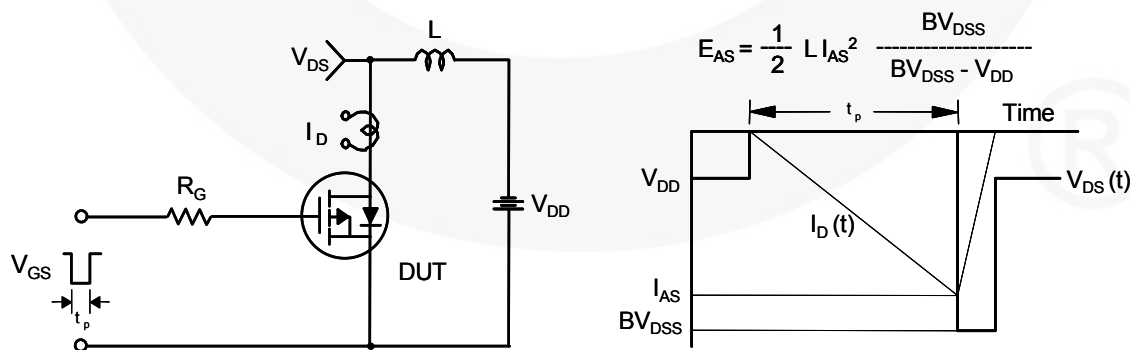


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

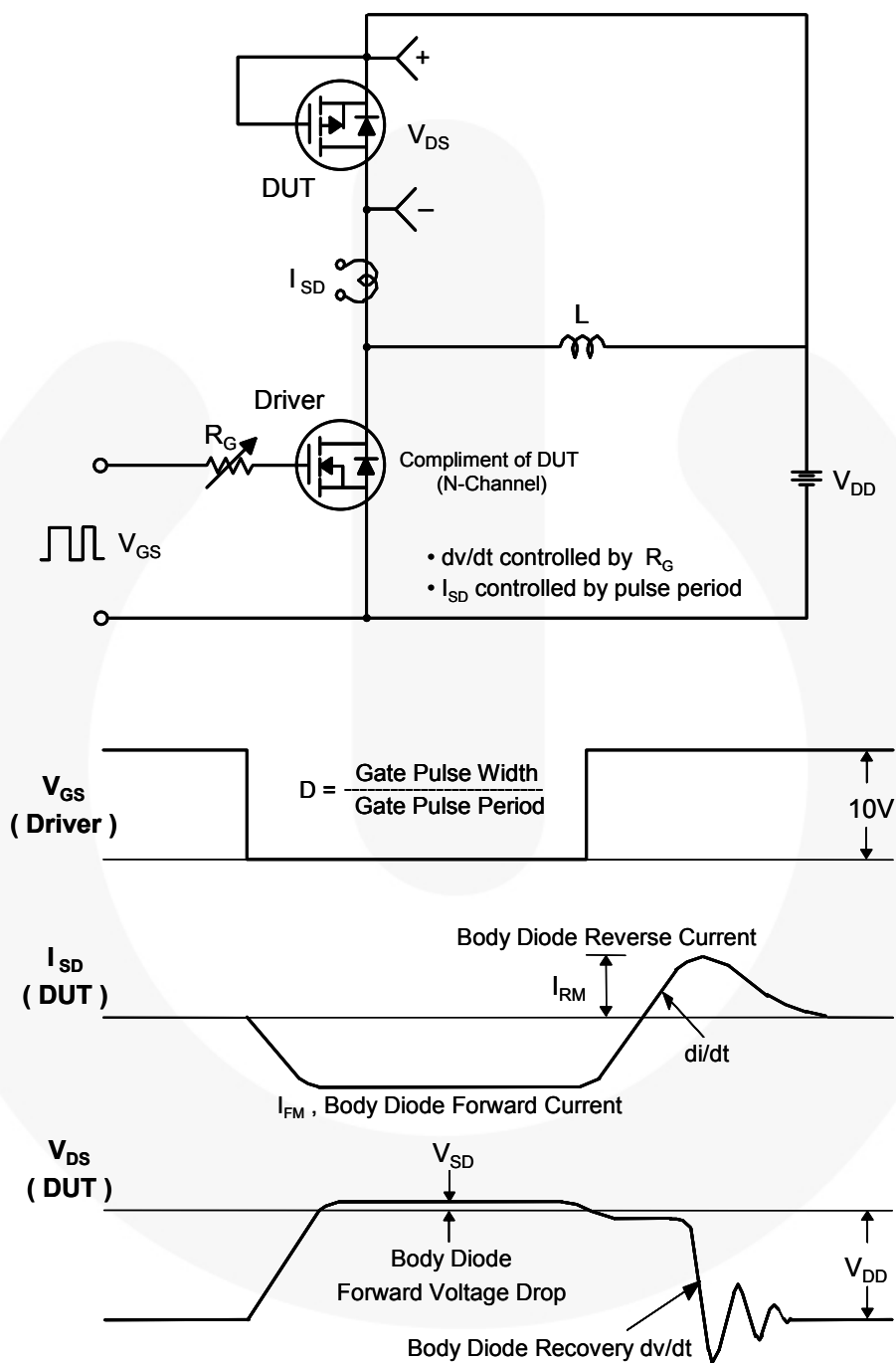


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Technical drawing of a TO254P1524X482-3N package showing top, front, and detail views with dimensions in millimeters.

Top View:

- Overall width: 10.67 (9.65)
- Overall height: 9.65 (8.38)
- Pin 1 location: (2.12)
- Pin 2 location: 1.78 MAX
- Pin 3 location: 1.78, 1.14, 0.99, 0.51
- Pin 4 location: 5.08
- Feature A: 1.68, 1.00
- Feature B: 0.25 (M), B, A(M)

Front View:

- Overall width: 12.70
- Overall height: 9.45
- Pin 1 location: 10.00 (6.40)
- Pin 2 location: 3.80
- Pin 3 location: 1.05
- Pin 4 location: 5.08
- Feature B: 4.83, 4.06
- Feature C: 1.65, 1.14
- Feature D: 15.88, 14.61
- Feature E: 0.10 (B)

Detail A (Rotated 90°):

- Overall width: 6.22 MIN
- Overall height: 6.86 MIN
- Pin 1 location: 0.25 MAX
- Pin 2 location: 0.74, 0.33
- Pin 3 location: 2.79, 1.78
- Pin 4 location: (5.38)
- Feature F: 8° 0'
- Feature G: 0.10 (B)

Notes:

- UNLESS OTHERWISE SPECIFIED
- A) ALL DIMENSIONS ARE IN MILLIMETERS.
- B) REFERENCE JEDEC, TO-263, VARIATION AB.
- C) DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.
- D) LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE).
- E) LANDPATTERN RECOMMENDATION PER IPC TO254P1524X482-3N
- F) FILENAME: TO263A02REV6

Figure 16: TO263 (D-PAK), Molded, 2-Lead, Surface Mount

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:
http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TT263-002



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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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